

STPS2200

Power Schottky diode

Datasheet – production data



- Low forward voltage drop
- Very small conduction losses
- Negligible switching losses
- Extremely fast switching
- Low thermal resistance
- -40°C minimum operating T_i
- ECOPACK[®]2 compliant component

Description

This device is a 200 V Schottky rectifier suited for switch mode power supplies and high frequency DC to DC converters.

Packaged in SMB, SMBflat, this device is especially intended for use in low voltage, high frequency inverters, freewheeling and polarity protection. Also ideal for all LED lighting applications.

K A A A A A A A SMB STPS2200U A A K SMBflat STPS2200UF

Table 1. Device summary

Symbol	Value
I _{F(AV)}	2 A
V _{RRM}	200 V
T _{j(max)}	175 °C
V _{F(typ)}	0.58 V

April 2013

1/9

This is information on a product in full production.

1 Characteristics

Table 2. Absolute ratings (limiting values, at 25 °C unless otherwise stated)

Symbol	Parameter	Value	Unit		
V _{RRM}	Repetitive peak reverse voltage		200	V	
I _{F(RMS)}	Forward rms current	10	А		
	Average ferward ourrent S 0.5 equare wave	SMB	T _I = 145 °C	2	А
^I F(AV)	Average forward current δ = 0.5, square wave	SMBflat	T _I = 150 °C	2	
I _{FSM}	Surge non repetitive forward current $t_p = 10 \text{ ms sinusoidal}, T_l = 25 \text{ °C}$			100	А
T _{stg}	Storage temperature range				°C
Тj	Operating junction temperature range		-40 to +175	°C	

Table 3. Thermal parameters

Symbol	Parameter	Value	Unit	
P	Junction to lead	SMB	20	°C/W
R _{th(j-l)}		SMBflat	15	0/14

Table 4. Static electrical characteristics

Symbol	Test conditions			Min.	Тур.	Max.	Unit
I _B ⁽¹⁾	Povorso loakago ourront	T _j = 25 °C	V _R = V _{RRM}			5	μA
'R`´	I _R ⁽¹⁾ Reverse leakage current	T _j = 125 °C			0.7	2.5	mA
V _E ⁽¹⁾		T _j = 25 °C	1 - 2 A		0.73	0.80	V
V _F Forward	Forward voltage drop	T _j = 125 °C	I _F = 2 A		0.58	0.64	V

1. Pulse test: t_p = 380 µs, δ < 2%

To evaluate the maximum conduction losses use the following equation: P = 0.58 x $I_{F(AV)}$ + 0.03 ${I_F}^2_{(RMS)}$

Note:More information is available in the application notes:AN604 Calculation of conduction losses in a power rectifierAN4021 Calculation of reverse losses in a power diode



Figure 1. Average forward power dissipation versus average forward current

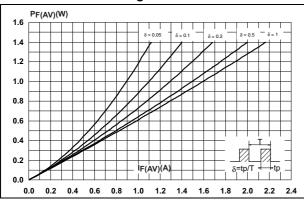


Figure 3. Reverse leakage current versus reverse voltage applied (typical values)

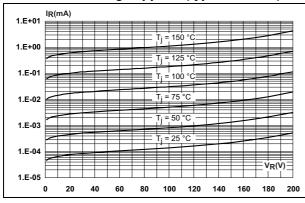


Figure 5. Relative variation of thermal impedance junction to lead versus pulse duration (SMB)

Figure 6. Relative variation of thermal impedance junction to lead versus pulse duration (SMBflat)

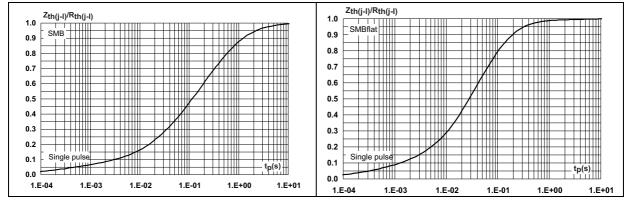


Figure 2. Forward voltage drop versus forward current

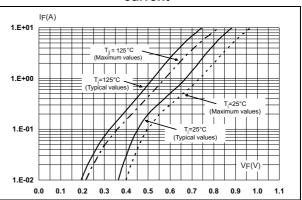


Figure 4. Junction capacitance versus reverse voltage applied (typical values)

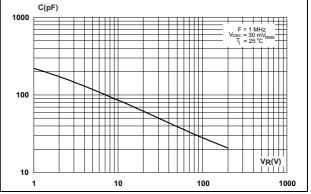
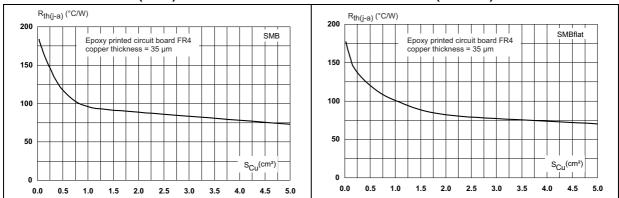


Figure 7. Thermal resistance junction to ambient versus copper surface under each lead ambient versus copper surface under each lead (SMB)

Figure 8. Thermal resistance junction to (SMBflat)





2 Package information

- Epoxy meets UL94, V0
- Lead-free package
- Cooling method: by conduction (C)
- Recommended torque value: 0.4 to 0.6 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK[®] is an ST trademark.

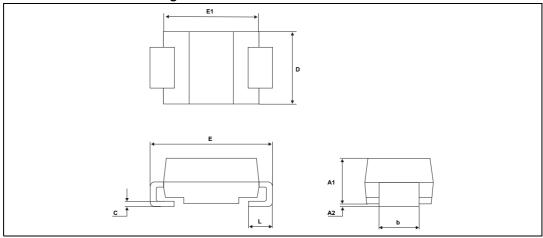


Table 5. SMB dimension values

	Dimensions					
Ref.		Millimeters			Inches	
	Min.	Тур.	Max.	Min.	Тур.	Max.
A1	1.90		2.45	0.075		0.096
A2	0.05		0.20	0.002		0.008
b	1.95		2.20	0.077		0.087
с	0.15		0.40	0.006		0.016
D	3.30		3.95	0.130		0.156
E	5.10		5.60	0.201		0.220
E1	4.05		4.60	0.159		0.181
L	0.75		1.50	0.030		0.059



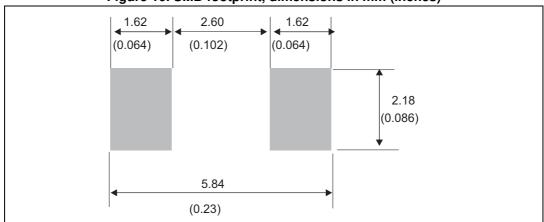


Figure 10. SMB footprint, dimensions in mm (inches)

Figure 11. SMBflat (non exposed pad) dimension definitions

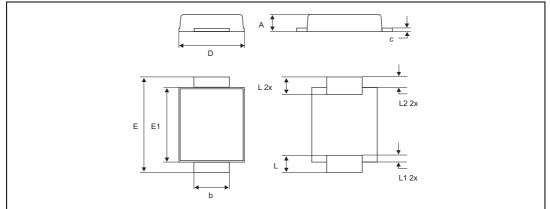


Table 6. SMBflat	(non ex	posed pad) dimension values
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	Dimensions						
Ref.	Millimeters			Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
А	0.90		1.10	0.035		0.043	
b	1.95		2.20	0.077		0.087	
С	0.15		0.40	0.006		0.016	
D	3.30		3.95	1.30		0.156	
E	5.10		5.60	0.200		0.220	
E1	4.05		4.60	0.189		0.181	
L	0.75		1.50	0.029		0.059	
L1		0.40			0.016		
L2		0.60			0.024		



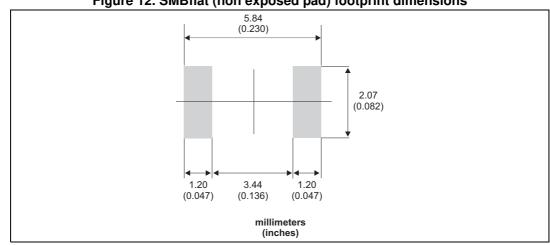


Figure 12. SMBflat (non exposed pad) footprint dimensions



3 Ordering information

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STPS2200U	G22	SMB	g	2500	Tape and reel
STPS2200UF	FG22	SMBflat	g	5000	Tape and reel

4 Revision history

Table 8. Document revision history

Date	Revision	Changes
11-Apr-2013	1	First issue



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DocID024381 Rev 1